

isc N-Channel MOSFET Transistor

IPD088N06N3G

• FEATURES

- With TO-252(DPAK) packaging
- With low gate drive requirements
- Very high commutation ruggedness
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

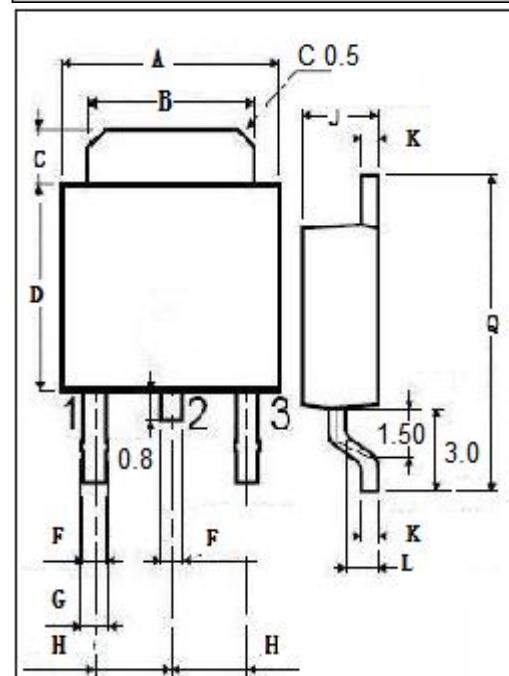
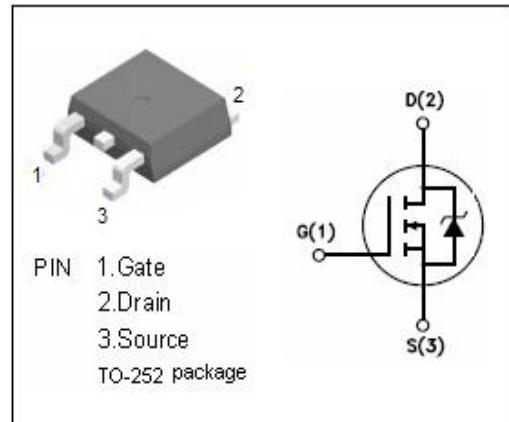
- Switching applications
- LCD&PDP TV
- PC silverbox
- UPS and solar

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	60	V
V_{GSS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous@ $T_c=25^\circ\text{C}$ $T_c=100^\circ\text{C}$	50 47	A
I_{DM}	Drain Current-Single Pulsed	200	A
P_D	Total Dissipation	71	W
T_j	Operating Junction Temperature	-55~175	°C
T_{stg}	Storage Temperature	-55~175	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	2.1	°C/W
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62	°C/W



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
F	0.65	
G	0.75	
H	2.10	2.50
J	2.10	2.40
K	0.40	0.60
L	0.90	1.10
Q	9.90	10.1

isc N-Channel MOSFET Transistor**IPD088N06N3G****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}; I_{\text{D}}= 1\text{mA}$	60			V
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}=\pm 20\text{V}; I_{\text{D}}=0.034\text{mA}$	2		4	V
$R_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$V_{\text{GS}}= 10\text{V}; I_{\text{D}}=50\text{A}$		7.1	8.8	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$V_{\text{GS}}= \pm 20\text{V}; V_{\text{DS}}= 0\text{V}$			± 0.1	$\mu\text{ A}$
I_{DSS}	Drain-Source Leakage Current	$V_{\text{DS}}= 60\text{V}; V_{\text{GS}}= 0\text{V}@T_j=25^\circ\text{C}$ $T_j=125^\circ\text{C}$			1 100	$\mu\text{ A}$
V_{SDF}	Diode forward voltage	$I_{\text{SD}}=50\text{A}, V_{\text{GS}} = 0 \text{ V}$			1.2	V

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